

INA296x-Q1 AEC-Q100, -5V to 110V, Bidirectional, 1.1MHz, 8V/µs, Ultra-Precise **Current Sense Amplifier**

1 Features

- AEC-Q100 qualified for automotive applications:
 - Temperature grade 1: −40°C to 125°C, T_A
- Functional Safety-Capable
 - Documentation available to aid functional safety system design
- Wide common-mode voltage:
 - Operational voltage: −5V to 110V
 - Survival voltage: -20V to 120V
- Bidirectional operation
- High small signal bandwidth: 1.1MHz (at all gains)
- Slew rate: 8V/µs
- Step response settling time to 1%: 1µs
- Excellent CMRR: 166dB
- Accuracy:
 - Gain error (maximum)
 - Version A: ±0.01%, ±1ppm/°C drift
 - Version B: ±0.1%, ±5ppm/°C drift
 - Offset voltage (maximum)
 - Version A: ±10µV, ±0.1µV/°C drift
 - Version B: ±150µV, ±0.5µV/°C drift
- Available gains:
 - INA296A1-Q1: 10V/V
 - INA296A2-Q1 : 20V/V
 - INA296A3-Q1 : 50V/V
 - INA296A4-Q1 : 100V/V
- INA296A5-Q1 : 200V/V
- Package options: SOT23-8, VSSOP-8, SOIC-8, VSSOP-10

2 Applications

- DC/DC converter
- Battery management systems (BMS)
- Fuel cell control unit
- Smart junction box

3 Description

The INA296x-Q1 is an ultra-precise, bidirectional current sense amplifier that can measure voltage drops across shunt resistors over a wide commonmode range from -5V to 110V, independent of the supply voltage. The high-precision current measurement is achieved through a combination of low offset voltage (±10µV, maximum), small gain error (±0.01%, maximum) and a high DC CMRR (typical 166dB). The INA296x-Q1 is not only designed for high voltage, bidirectional DC current measurements, but also for high-speed applications (such as transient detection and fast overcurrent protection) with a high signal bandwidth of 1.1MHz and fast settling time.

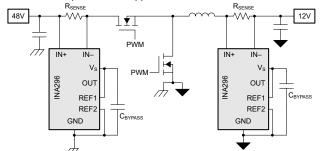
The INA296x-Q1 operates from a single 2.7V to 20V supply, drawing 2.5mA of supply current. The INA296x-Q1 is available in five gain options: 10V/V, 20V/V, 50V/V, 100V/V, and 200V/V. Multiple gain options allow for optimization between available shunt resistor values and wide output dynamic range requirements.

INA296x-Q1 is specified operating over temperature range of -40°C to 125°C.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
	DDF (SOT-23, 8)	2.9mm × 2.8mm
INA296A-Q1	DGK (VSSOP, 8)	3mm × 4.9mm
INA296B-Q1	D (SOIC, 8)	4.9mm × 6mm
	DGS (VSSOP, 10)	3mm × 4.9mm

- For all available packages, see the package option addendum at the end of the data sheet.
- The package size (length × width) is a nominal value and includes pins, where applicable.



Typical Application - DC/DC Converter



Table of Contents

1 Features	1	7.4 Device Functional Modes	16
2 Applications	1	8 Application and Implementation	21
3 Description		8.1 Application Information	21
4 Device Comparison	<mark>2</mark>	8.2 Typical Application	<mark>22</mark>
5 Pin Configuration and Functions		8.3 Power Supply Recommendations	23
6 Specifications	4	8.4 Layout	23
6.1 Absolute Maximum Ratings	4	9 Device and Documentation Support	
6.2 ESD Ratings		9.1 Documentation Support	25
6.3 Recommended Operating Conditions		9.2 Receiving Notification of Documentation Updates	s25
6.4 Thermal Information	4	9.3 Support Resources	25
6.5 Electrical Characteristics	<mark>5</mark>	9.4 Trademarks	25
6.6 Typical Characteristics	8	9.5 Electrostatic Discharge Caution	25
7 Detailed Description		9.6 Glossary	25
7.1 Overview		10 Revision History	
7.2 Functional Block Diagram	15	11 Mechanical, Packaging, and Orderable	
7.3 Feature Description	15	Information	26
•			

4 Device Comparison

Table 4-1. Device Comparison

DEVICE NAME	GAIN
INA296A1-Q1, 1INA296B1-Q1	10V/V
INA296A2-Q1, 1INA296B2-Q1	20V/V
INA296A3-Q1, 1INA296B3-Q1	50V/V
INA296A4-Q1, 1INA296B4-Q1	100V/V
INA296A5-Q1, 1INA296B5-Q1	200V/V

5 Pin Configuration and Functions



Figure 5-1. INA296x-Q1: DDF Package 8-Pin SOT-23 Top View

Figure 5-2. INA296x-Q1: D and DGK Package 8-Pin SOIC and 8-Pin VSSOP Top View

Table 5-1. Pin Functions: D, DDF and DGK Packages

P	IN	TYPE	DESCRIPTION		
NAME	NO.	1175	DESCRIP HON		
GND	2	Ground	Ground.		
IN+	8	Input	Current-sense amplifier positive input. For high-side applications, connect to bus-voltage side of sense resistor. For low-side applications, connect to load side of sense resistor.		
IN-	1	Input	Current-sense amplifier negative input. For high-side applications, connect to load side of sense resistor. For low-side applications, connect to ground side of sense resistor.		
NC	4	Ground	Reserved. Connect to ground.		
OUT	5	Output	Output voltage.		

Submit Document Feedback

IN+

REF1

۷s

OUT

Table 5-1. Pin Functions: D, DDF and DGK Packages (continued)

	rabio o in in anomono o, bor ana bort abiagos (borianada)					
P	PIN	TYPE	DESCRIPTION			
NAME	NO.	1175	DESCRIPTION			
REF1	7	Input	Reference 1 voltage. Connect to voltage potential from 0V to V _S ; see <i>Adjusting the Output With the Reference Pins</i> for connection options.			
REF2	3	Input	Reference 2 voltage. Connect to voltage potential from 0V to V _S ; see <i>Adjusting the Output With the Reference Pins</i> for connection options.			
Vs	6	Power	Power supply, 2.7V to 20V			

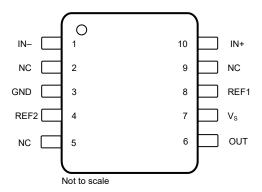


Figure 5-3. INA296x-Q1: DGS Package 10-Pin VSSOP Top View

Table 5-2. Pin Functions: DGS Package

	PIN	TYPE	DESCRIPTION
NAME	NO.	ITPE	DESCRIPTION
GND	3	Ground	Ground
IN+	10	Input	Current-sense amplifier positive input. For high-side applications, connect to bus-voltage side of sense resistor. For low-side applications, connect to load side of sense resistor.
IN-	1	Input	Current-sense amplifier negative input. For high-side applications, connect to load side of sense resistor. For low-side applications, connect to ground side of sense resistor.
NC	5	Ground	Reserved. Connect to ground.
NC	2	_	Leave unconnected
NC	9	_	Leave unconnected
OUT	6	Output	Output voltage
REF1	8	Input	Reference 1 voltage. Connect to voltage potential from 0V to V _S ; see <i>Adjusting the Output With the Reference Pins</i> for connection options.
REF2	4	Input	Reference 2 voltage. Connect to voltage potential from 0V to V_S ; see <i>Adjusting the Output With the Reference Pins</i> for connection options.
Vs	7	Power	Power supply, 2.7V to 20V

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Supply voltage (V _S)			22	V
Analog inputs,	Differential (V _{IN+}) - (V _{IN-})	-30	30	V
V _{IN+} , V _{IN-} (2)	Common-mode	-20	120	
REF1, REF2, NC inputs		GND - 0.3	V _S + 0.3	V
Output		GND - 0.3	Vs + 0.3	V
T _A	Operating temperature	– 55	150	°C
TJ	Junction temperature		150	°C
T _{stg}	Storage temperature	-65	150	°C

⁽¹⁾ Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

6.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 ⁽¹⁾ HBM ESD classification level 2	±2000	
V _(ESD)	Electrostatic discriarge	Charged device model (CDM), per AEC Q100-011 CDM ESD classification level C6	±1000	v

⁽¹⁾ AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{CM}	Common-mode input range	-5	48	110	V
Vs	Operating supply range	2.7	5	20	V
T _A	Ambient temperature	-40		125	°C

6.4 Thermal Information

		INA296x-Q1				
THERMAL METRIC(1)		DDF (SOT23)	DGK (VSSOP)	D (SOIC)	DGS (VSSOP)	UNIT
		8 PINS	8 PINS	8 PINS	10 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	129.7	167.2	122.9	143.3	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	58	58.9	54.7	49.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	52.6	88.9	68.8	80	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	2.3	8.1	12.2	2.6	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	52.3	87.4	67.5	78.6	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application note.

Submit Document Feedback

Copyright © 2024 Texas Instruments Incorporated

⁽²⁾ V_{IN+} and V_{IN-} are the voltages at the IN+ and IN- pins, respectively.

6.5 Electrical Characteristics

 $\underline{\text{at T}_{\text{A}} = 25 \text{ °C, V}_{\text{S}} = 5\text{V, V}_{\text{SENSE}} = \text{V}_{\text{IN+}} - \text{V}_{\text{IN-}}, \text{V}_{\text{CM}} = \text{V}_{\text{IN-}} = 48\text{V, and V}_{\text{REF1}} = \text{V}_{\text{REF2}} = \text{V}_{\text{S}} \text{ / 2 (unless otherwise noted)}$

at i A	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
INPUT								
V _{CM}	Common-mode input range ⁽¹⁾	V _{IN+} , V _{IN-} = -5V to 110V, V _{SENSE} = 0mV T _A = -40°C to 125°C	-5		110	V		
	Common-mode rejection ratio, input- referred	V _{IN+} , V _{IN-} = -5V to 110V, V _{SENSE} = 0mV T _A = -40°C to 125°C, INA296A-Q1	150	166				
CMRR		V _{IN+} , V _{IN-} = -5V to 110V, V _{SENSE} = 0mV T _A = -40°C to 125°C, INA296B-Q1	120	130		dB		
		f = 50kHz		105				
		V _{SENSE} = 0mV, INA296A1-Q1		±5	±20			
		V _{SENSE} = 0mV, INA296A2-Q1		±3	±15			
V _{os}	Offset voltage, input-referred	V _{SENSE} = 0mV, INA296A3-Q1, INA296A4-Q1		±3	±10	μV		
		V _{SENSE} = 0mV, INA296A5-Q1		±2	±8			
		V _{SENSE} = 0mV, INA296B-Q1		±25	±150			
		$T_A = -40$ °C to 125°C, INA296A1-Q1		±50	±250			
	Offset voltage drift, input-referred	$T_A = -40$ °C to 125°C, INA296A2-Q1		±30	±150			
dV _{os} /dT		T _A = -40°C to 125°C, INA296A3-Q1, INA296A4-Q1, INA296A5-Q1		±20	±100	nV/°C		
		T _A = -40°C to 125°C, INA296B-Q1		±100	±500			
	Power-supply rejection ratio, input-referred	$V_S = 2.7V \text{ to } 20V, V_{SENSE} = 0\text{mV}, V_{REF1} = V_{REF2} = 1V, T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}, INA296A1-Q1$		±0.2	±1			
		$V_S = 2.7V \text{ to } 20V, V_{SENSE} = 0\text{mV},$ $V_{REF1} = V_{REF2} = 1V,$ $T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}, \text{ INA296A2-Q1}$		±0.1	±0.75	μV/V		
PSRR		V_S = 2.7V to 20V, V_{SENSE} = 0mV, V_{REF1} = V_{REF2} = 1V, T_A = -40°C to 125°C, INA296A3-Q1, INA296A4-Q1, INA296A5-Q1		±0.06	±0.5			
		$V_S = 2.7V \text{ to } 20V, V_{SENSE} = 0\text{mV}, V_{REF1} = V_{REF2} = 1V, T_A = -40^{\circ}\text{C to } 125^{\circ}\text{C}, INA296B-Q1$		±1	±10			
I _B	Input bias current	I _{B+} , I _{B-} , V _{SENSE} =0mV	25	35	45	μA		
	Reference input range		0		Vs	V		
OUTPUT								
		A1, B1 Devices		10		V/V		
		A2, B2 Devices		20		V/V		
G	Gain	A3, B3 Devices		50		V/V		
İ		A4, B4 Devices		100		V/V		
		A5, B5 Devices		200		V/V		

	PARAMETER	$C_{CM} = V_{IN-} = 48V$, and $V_{REF1} = V_{REF2} = V_{S}$ TEST CONDITIONS	MIN TYP	MAX	UNIT
		(GND + 50mV) < V _{OUT} < (V _S - 200mV), INA296A1-Q1, INA296A2-Q1, INA296A3- Q1	±0.002	±0.01	
	Gain Error	(GND + 50mV) < V _{OUT} < (V _S - 200mV), INA296A4-Q1, INA296A5-Q1	±0.003	±0.015	%
G _{ERR}		(GND + 50mV) < V _{OUT} < (V _S - 200mV), INA296B-Q1	±0.02	±0.1	
		T _A = -40°C to +125°C, INA296A1-Q1, INA296A2-Q1, INA296A3- Q1	±0.05	±1	ppm/°C
	Gain Error Drift	T _A = -40°C to +125°C, INA296A4-Q1, INA296A5-Q1	±0.1	±2	
		T _A = -40°C to +125°C, INA296B-Q1	±0.2	±5	
	Non-Linearity Error		±0.001		%
	Maximum Capacitive Load	No sustained oscillations, No isolation resistor	1		nF
VOLTAG	E OUTPUT				
	Swing to V _S Power Supply Rail	$R_L = 10k\Omega$ to GND, $T_A = -40^{\circ}$ C to +125°C	V _S - 0.07	V _S - 0.2	V
	Swing to Ground	$R_L = 10k\Omega$ to GND, $V_{SENSE} = 0$ mV, $V_{REF1} = V_{REF2} = 0$ V, $T_A = -40$ °C to +125°C	8	20	mV
REFERE	NCE INPUT				
		$V_{REF1} = V_{REF2} = 0.5V \text{ to } 4.5V,$ $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C, INA296A1-Q1,}$	±1	±2.5	
RVRR	Reference voltage rejection ratio, input- referred	$V_{REF1} = V_{REF2} = 0.5V$ to 4.5V, $T_A = -40^{\circ}\text{C}$ to +125°C, INA296A2-Q1, INA296A3-Q1, INA296A4-Q1, INA296A5-Q1	±0.5	±1.5	μV/V
		V _{REF1} = V _{REF2} = 0.5V to 4.5V, T _A = -40°C to +125°C, INA296B-Q1	±10	±20	
		$\begin{split} &V_{OUT} = (V_{REF1} + V_{REF2}) \ / \ 2 \ at \ V_{SENSE} \\ = &0 mV, \\ &V_{REF1} = V_S, \ V_{REF2} = GND \\ &V_{REF1} = GND, \ V_{REF2} = V_S \\ &T_A = -40^{\circ}C \ to \ +125^{\circ}C, \ INA296A1-Q1, \\ &INA296A2-Q1, \end{split}$	±0.002	±0.005	
	Reference divider accuracy	$\begin{split} &V_{OUT} = (V_{REF1} + V_{REF2}) \ / \ 2 \ at \ V_{SENSE} \\ = &0 mV, \\ &V_{REF1} = V_S, \ V_{REF2} = GND \\ &V_{REF1} = GND, \ V_{REF2} = V_S \\ &T_A = -40^{\circ}C \ to \ +125^{\circ}C, \ INA296A3-Q1, \\ &INA296A4-Q1, \ INA296A5-Q1 \end{split}$	±0.002	±0.01	%
		V _{OUT} = (V _{REF1} + V _{REF2}) / 2 at V _{SENSE} =0mV, V _{REF1} = V _S , V _{REF2} = GND V _{REF1} = GND, V _{REF2} = V _S T _A = -40°C to +125°C, INA296B-Q1	±0.02	±0.15	
FREQUE	ENCY RESPONSE				
BW	Bandwidth	All Gains, -3dB Bandwidth	1.1		MHz

at $T_A = 25$ °C, $V_S = 5V$, $V_{SENSE} = V_{IN+} - V_{IN-}$, $V_{CM} = V_{IN-} = 48V$, and $V_{REF1} = V_{REF2} = V_S / 2$ (unless otherwise noted)

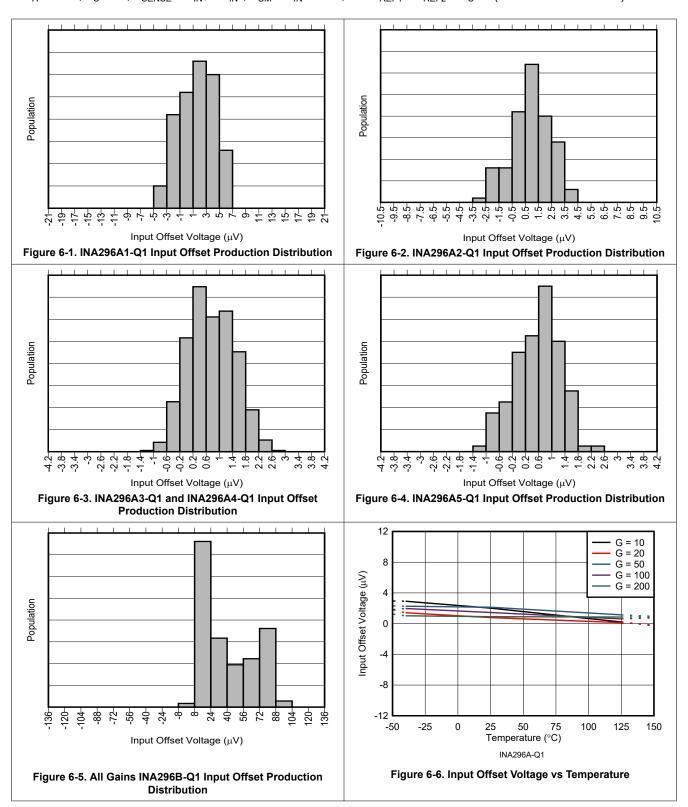
GL 1A	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		V _{IN+} , V _{IN-} = 48V, V _{OUT} = 0.5V to 4.5V, Output settles to 0.5%		1.5		μs
	Settling time	$V_{\text{IN+}}$, $V_{\text{IN-}}$ = 48V, V_{OUT} = 0.5V to 4.5V, Output settles to 1%		1		μs
		$V_{\text{IN+}}$, $V_{\text{IN-}}$ = 48V, V_{OUT} = 0.5V to 4.5V, Output settles to 5%		0.5		μs
SR	Slew Rate	Rising		8		V/µs
NOISE	(Input referred)				'	
		A1, B1 Devices		62		
		A2, B2 Devices		49		
	Voltage noise density	A3, B3 Devices		39		
		A4, B4 Devices		36		
		A5, B5 Devices	28			
POWE	R SUPPLY					
Vs	Supply Voltage		2.7		20	V
		V _{SENSE} = 0mV		2.5	3	mA
IQ	Quiescent current	V _{SENSE} = 0mV, T _A = -40°C to +125°C			3.2	mA
TEMPI	ERATURE		•	,		
T _A	Specified Range		-40		125	°C
	<u> </u>					

⁽¹⁾ Common-mode voltage at both $V_{\text{IN+}}$ and $V_{\text{IN-}}$ must not exceed the specified common-mode input range.

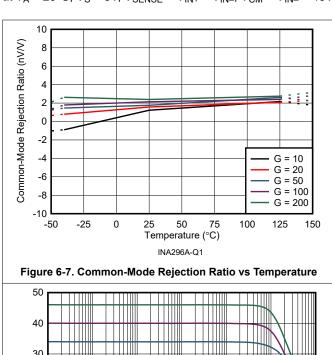


6.6 Typical Characteristics

at $T_A = 25$ °C, $V_S = 5$ V, $V_{SENSE} = V_{IN+} - V_{IN-}$, $V_{CM} = V_{IN-} = 48$ V, and $V_{REF1} = V_{REF2} = V_S$ / 2 (unless otherwise noted)



at $T_A = 25$ °C, $V_S = 5$ V, $V_{SENSE} = V_{IN+} - V_{IN-}$, $V_{CM} = V_{IN-} = 48$ V, and $V_{REF1} = V_{REF2} = V_S$ / 2 (unless otherwise noted)



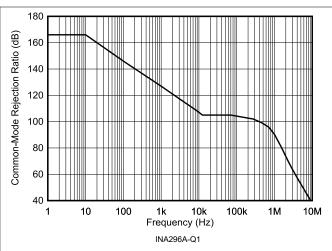
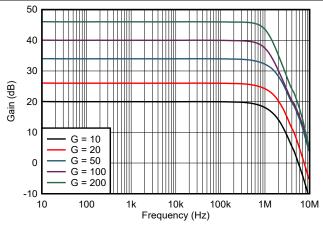


Figure 6-8. Common-Mode Rejection Ratio vs Frequency



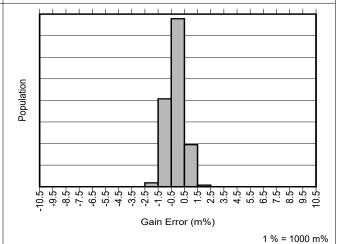
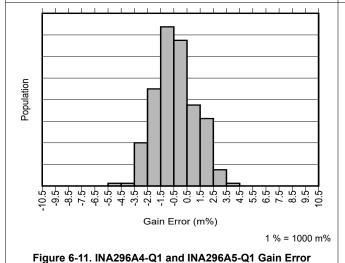


Figure 6-9. Gain vs Frequency

Figure 6-10. INA296A1-Q1, INA296A2-Q1 and INA296A3-Q1 Gain Error Production Distribution



Production Distribution

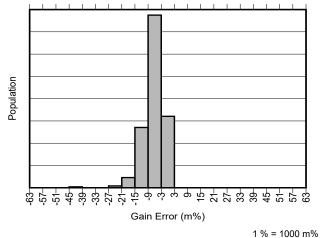


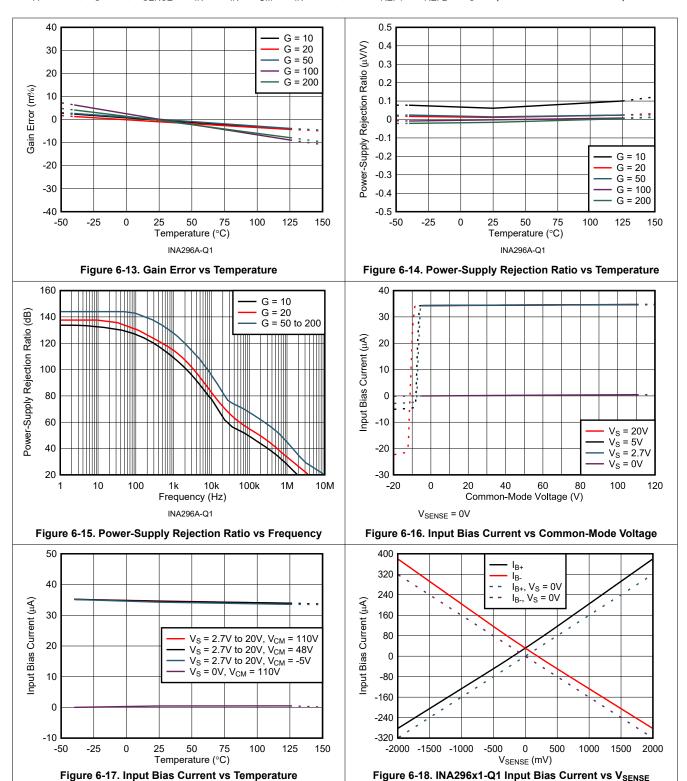
Figure 6-12. All Gains INA296B-Q1 Gain Error Production Distribution

Copyright © 2024 Texas Instruments Incorporated

Submit Document Feedback



at $T_A = 25$ °C, $V_S = 5$ V, $V_{SENSE} = V_{IN+} - V_{IN-}$, $V_{CM} = V_{IN-} = 48$ V, and $V_{REF1} = V_{REF2} = V_S$ / 2 (unless otherwise noted)

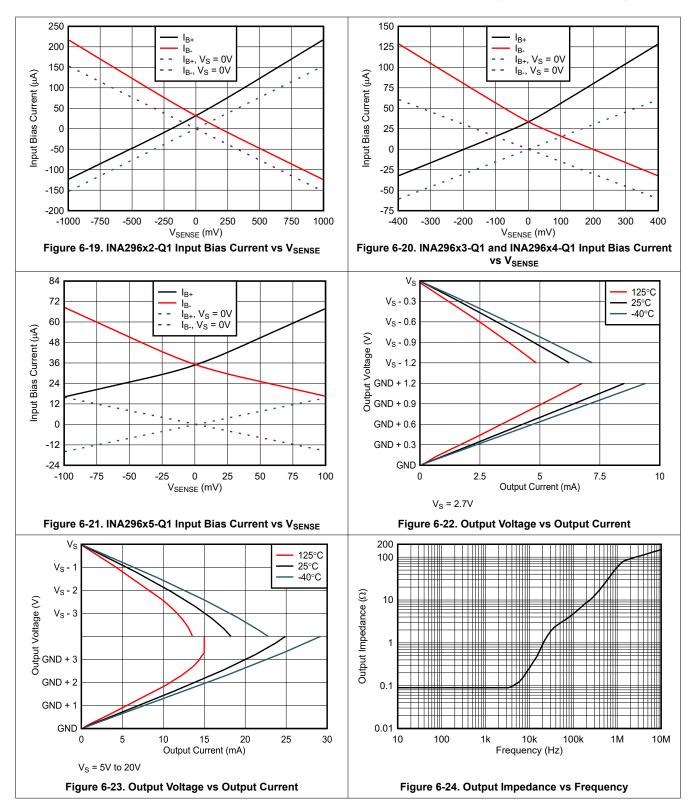


Submit Document Feedback

Copyright © 2024 Texas Instruments Incorporated

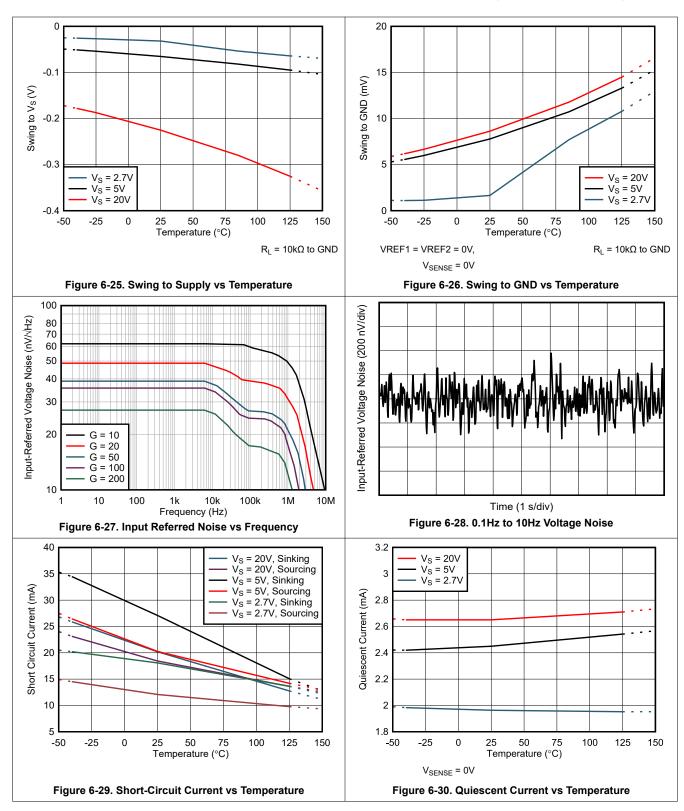


at $T_A = 25$ °C, $V_S = 5$ V, $V_{SENSE} = V_{IN+} - V_{IN-}$, $V_{CM} = V_{IN-} = 48$ V, and $V_{REF1} = V_{REF2} = V_S / 2$ (unless otherwise noted)



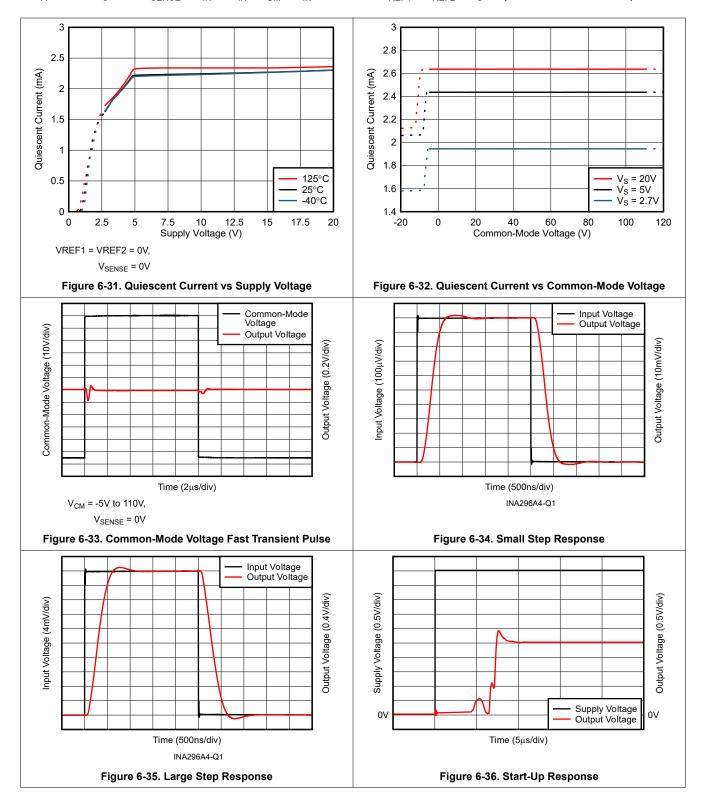


at T_A = 25°C, V_S = 5V, V_{SENSE} = V_{IN+} – V_{IN-} , V_{CM} = V_{IN-} = 48V, and V_{REF1} = V_{REF2} = V_S / 2 (unless otherwise noted)



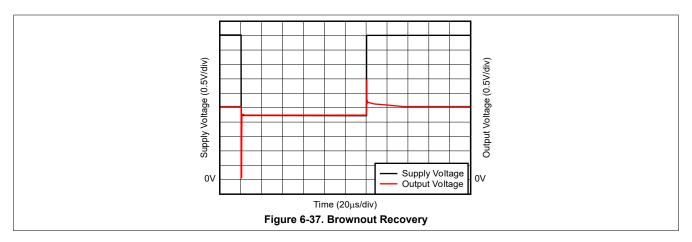


at $T_A = 25$ °C, $V_S = 5$ V, $V_{SENSE} = V_{IN+} - V_{IN-}$, $V_{CM} = V_{IN-} = 48$ V, and $V_{REF1} = V_{REF2} = V_S / 2$ (unless otherwise noted)





at T_A = 25°C, V_S = 5V, V_{SENSE} = V_{IN+} – V_{IN-} , V_{CM} = V_{IN-} = 48V, and V_{REF1} = V_{REF2} = V_S / 2 (unless otherwise noted)



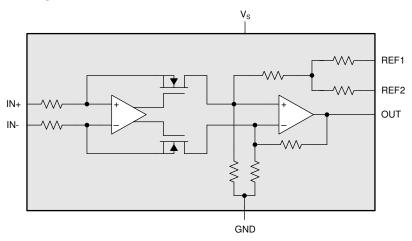


7 Detailed Description

7.1 Overview

The INA296x-Q1 is a high-side, inline, or low-side bidirectional, high-speed current-sense amplifier that offers a wide common-mode range, precision zero-drift topology, excellent common-mode rejection ratio (CMRR) and fast slew rate. Different gain versions are available to optimize the output dynamic range based on the application. The INA296x-Q1 is designed using an architecture that enables low bias currents of 35μA with a specified common-mode voltage range from –5V to 110V with signal bandwidths up to 1.1MHz.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Amplifier Input Common-Mode Signal

The INA296x-Q1 supports large input common-mode voltages from -5V to 110V. The internal topology of the INA296x-Q1 allows the common-mode range to exceed the power-supply voltage (V_S). This allows for the INA296x-Q1 to be used for low-side, inline, and high-side current-sensing applications that extend beyond the supply range of 2.7V to 20V.

7.3.1.1 Input-Signal Bandwidth

The INA296x-Q1 is available with several gain options including 10V/V, 20V/V, 50V/V, 100V/V, and 200V/V. The unique multistage design enables the amplifier to achieve high bandwidth of 1.1MHz at all gains. This high bandwidth provides the throughput and fast response that is required for the rapid detection and processing of over-current events.

7.3.1.2 Low Input Bias Current

The INA296x-Q1 inputs draw 35μA (typical) bias current per input pin at common-mode voltages as high as 110V, which enables precision current sensing on applications that require lower current leakage. Unlike many high voltage current sense amplifiers whose input bias currents are proportional to the common-mode voltage, the input bias current of the INA296x-Q1 remains constant over the entire common-mode voltage range.

7.3.1.3 Low V_{SENSE} Operation

The INA296x-Q1 features high performance operation across the entire valid V_{SENSE} range. The zero-drift input architecture of the INA296x-Q1 provides the low offset voltage and low offset drift needed to measure low V_{SENSE} levels accurately across the wide operating temperature of -40° C to $+125^{\circ}$ C. Low V_{SENSE} operation is particularly beneficial when using low ohmic shunts for low current measurements, as power losses across the shunt are significantly reduced.

7.3.1.4 Wide Fixed Gain Output

The INA296x-Q1 maximum gain error is $\pm 0.01\%$ at room temperature, with a maximum drift of ± 1 ppm/°C over the full temperature range of -40°C to 125°C. The INA296x-Q1 is available in multiple gain options of 10V/V,

20V/V, 50V/V, 100V/V, and 200V/V, which the system designer must select based on the desired signal-to-noise ratio and other system requirements, such as the dynamic current range and full-scale output voltage target.

7.3.1.5 Wide Supply Range

The INA296x-Q1 operates with a wide supply range from 2.7V to 20V. While the input common-mode voltage range of the INA296x-Q1 is independent of the supply voltage, the output voltage is bound by the supply voltage applied to the device. The output voltage can range from as low as 20mV to as high as 200mV below the supply voltage.

7.4 Device Functional Modes

7.4.1 Adjusting the Output With the Reference Pins

Figure 7-1 shows a test circuit for reference-divider accuracy. The INA296x-Q1 output is configurable to allow for unidirectional or bidirectional operation.

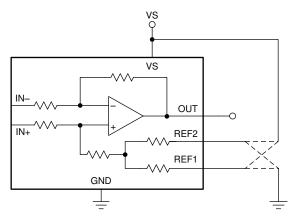


Figure 7-1. Test Circuit For Reference Divider Accuracy

The output voltage is set by applying a voltage or voltages to the reference voltage inputs, REF1 and REF2. The reference inputs are connected to an internal gain network. There is no operational difference between the two reference pins. The resistor network connected to the two reference pins are designed with ultra-precision and matching. Output is set accurately at the mid-point voltage between the voltages applied to reference voltage inputs, when current-sense input voltage is 0V as shown in Equation 1. In most bidirectional applications, one reference input is connected to the positive supply and the other reference input is connected to the negative supply (GND pin) to set the output voltage to mid-supply.

$$V_{OUT} = G \times (V_{IN} + V_{IN} - V_{I$$

7.4.2 Reference Pin Connections for Unidirectional Current Measurements

Unidirectional operation allows current measurements through a resistive shunt in one direction. For unidirectional operation, connect the device reference pins together and then to the negative rail (see the *Ground Referenced Output* section) or the positive rail (see the *VS Referenced Output* section). The required differential input polarity depends on the reference input setting. The amplifier output moves away from the referenced rail proportional to the current passing through the external shunt resistor. If the amplifier reference pins are connected to the positive rail, then the input polarity must be negative to move the amplifier output down (towards ground). If the amplifier reference pins are connected to ground, then the input polarity must be positive to move the amplifier output up (towards supply).

The following sections describe how to configure the output for unidirectional operation cases.

7.4.2.1 Ground Referenced Output

When using the INA296x-Q1 in a unidirectional mode with a ground referenced output, both reference inputs are connected to ground. This configuration takes the output to ground when there is a 0V differential at the input (see Figure 7-2).

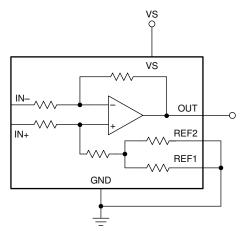


Figure 7-2. Ground Referenced Output

7.4.2.2 VS Referenced Output

Unidirectional mode with a VS referenced output is configured by connecting both reference pins to the positive supply. Use this configuration for circuits that require power up and stabilization of the amplifier output signal and other control circuitry before power is applied to the load (see Figure 7-3).

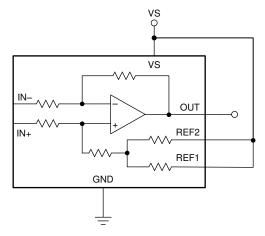


Figure 7-3. VS Referenced Output

7.4.3 Reference Pin Connections for Bidirectional Current Measurements

The INA296x-Q1 measures the differential voltage developed by current flowing through a resistor, commonly referred to as a current-sensing resistor or a current-shunt resistor. The INA296x-Q1 can operate in either a unidirectional or bidirectional mode based on the voltage potential placed on the reference pins.

The linear range of the output stage is limited to how close the output voltage can approach ground as well the supply voltage as described in the *Specifications*. The selection of the current-sensing resistor along with the current range to be measured, selection of the gain option, as well as the voltage applied to the reference pins must be selected to keep the INA296x-Q1 within the linear region of operation.

7.4.3.1 Output Set to External Reference Voltage

Connecting both pins together and then to a reference voltage results in an output voltage equal to the reference voltage for the condition of shorted input pins or a 0V differential input. Figure 7-4 shows this configuration. The output voltage decreases below the reference voltage when the IN+ pin is negative relative to the IN- pin and increases when the IN+ pin is positive relative to the IN- pin. This technique is the most accurate way to bias the output to a precise voltage.

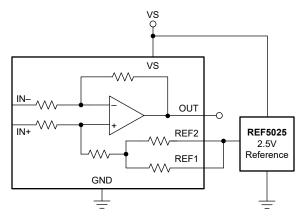


Figure 7-4. External Reference Output

7.4.3.2 Output Set to Mid-Supply Voltage

By connecting one reference pin to VS and the other to the GND pin, Figure 7-5 shows that the output is set at half of the supply voltage when there is no differential input. This method creates a ratiometric offset to the supply voltage, where the output voltage remains at VS / 2 for 0V applied to the inputs.

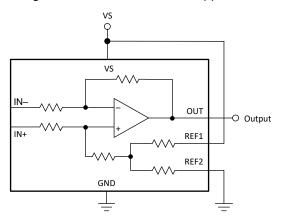


Figure 7-5. Mid-Supply Voltage Output

7.4.3.3 Output Set to Mid-External Reference

In this case, Figure 7-6 shows how an external reference can divided by two by connecting one REF pin to ground and the other REF pin to the reference.

Submit Document Feedback

Copyright © 2024 Texas Instruments Incorporated



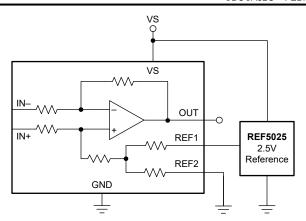


Figure 7-6. Mid-External Reference Output

7.4.3.4 Output Set Using Resistor Divider

The INA296x-Q1 reference pins allow for the mid-point of the output voltage to be adjusted for system circuitry connections to analog to digital converters (ADCs) or other amplifiers. The reference pins are designed to be connected directly to supply, ground, or a low-impedance reference voltage. The reference pins can be connected together and biased using a resistor divider to achieve a custom output voltage. If the amplifier is used in this configuration, as shown in Figure 7-7, use the output as a differential signal with respect to the resistor divider voltage. Use of the amplifier output as a single-ended signal in this configuration is not recommended because the internal impedance shifts can adversely affect device performance specifications. If single-ended measurement is required, TI recommends to use an external op amp to buffer the resistor divider voltage (see Figure 7-8).

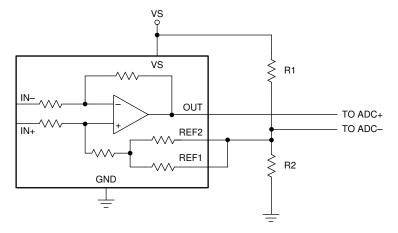


Figure 7-7. Setting the Reference Using a Resistor Divider



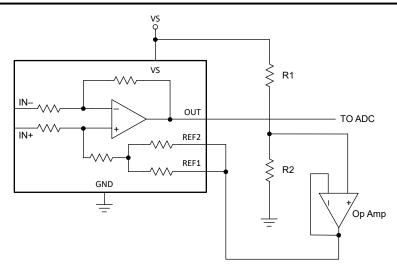


Figure 7-8. Setting the Reference Using a Resistor Divider and an Op Amp Buffer

7.4.4 High Signal Throughput

With a bandwidth of 1.1MHz at a gain of 20V/V and a slew rate of 8V/ μ s, the INA296x-Q1 is specifically designed for detecting and protecting applications from fast inrush currents. As shown in Table 7-1, the INA296x-Q1 responds in less than 1 μ s for a system measuring a 75A threshold on a 2m Ω shunt.

Table 7-1. Response Time

	1 413	io i ii itooponoo iiiio	
	PARAMETER	EQUATION	INA296x-Q1 AT $V_S = 5V$
G	Gain		20V/V
I _{MAX}	Maximum current		100A
I _{Threshold}	Threshold current		75A
R _{SENSE}	Current sense resistor value		2mΩ
V _{OUT_MAX}	Output voltage at maximum current	$V_{OUT_MAX} = I_{MAX} \times R_{SENSE} \times G$	4V
V _{OUT_THR}	Output voltage at threshold current	V _{OUT_THR} = I _{THR} × R _{SENSE} × G	3V
SR	Slew rate		8V/µs
T _{response}	Output response time	T _{response} = V _{OUT_THR} / SR	< 1µs

Submit Document Feedback

Copyright © 2024 Texas Instruments Incorporated



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The INA296x-Q1 amplifies the voltage developed across a current-sensing resistor as current flows through the resistor to the load. The wide input common-mode voltage range and high common-mode rejection of the INA296x-Q1 make the device usable over a wide range of voltage rails while still maintaining an accurate current measurement.

8.1.1 R_{SENSE} and Device Gain Selection

The accuracy of any current-sense amplifier is maximized by choosing the largest current-sense resistor value possible. A larger value sense resistor maximizes the differential input signal for a given amount of current flow and reduces the error contribution of the offset voltage. However, there are practical limits as to how large the current-sense resistor value can be in a given application because of the physical dimensions of the package, package construction, and maximum power dissipation. Equation 2 gives the maximum value for the current-sense resistor for a given power dissipation budget:

$$R_{SENSE} < \frac{PD_{MAX}}{I_{MAX}^2} \tag{2}$$

where:

- PD_{MAX} is the maximum allowable power dissipation in R_{SENSE}.
- I_{MAX} is the maximum current that flows through R_{SENSE}.

An additional limitation on the size of the current-sense resistor and device gain is due to the power-supply voltage, V_S , and device swing-to-rail limitations. To make sure that the current-sense signal is properly passed to the output, both positive and negative output swing limitations must be examined. Equation 3 provides the maximum values of R_{SENSE} and GAIN to keep the device from exceeding the positive swing limitation.

$$I_{MAX} \times R_{SENSE} \times GAIN < V_{SP}$$
 (3)

where:

- I_{MAX} is the maximum current that flows through R_{SENSE}.
- · GAIN is the gain of the current-sense amplifier.
- V_{SP} is the positive output swing of the device as specified in the Specifications.

To avoid positive output swing limitations when selecting the value of R_{SENSE}, there is always a trade-off between the value of the sense resistor and the gain of the device under consideration. If the sense resistor selected for the maximum power dissipation is too large, then selecting a lower gain device is possible to avoid positive swing limitations.

The negative swing limitation places a limit on how small the sense resistor value can be for a given application. Equation 4 provides the limit on the minimum value of the sense resistor.

$$I_{MIN} \times R_{SENSE} \times GAIN > V_{SN}$$
 (4)

where:

- I_{MIN} is the minimum current that flows through R_{SENSE}.
- GAIN is the gain of the current-sense amplifier.
- V_{SN} is the negative output swing of the device as specified in the Specifications.

Table 8-1 shows an example of the different results obtained from using five different gain versions of the INA296x-Q1. From the table data, the highest gain device allows a smaller current-shunt resistor and decreased power dissipation in the element.

Table 8-1. R_{SENSE} Selection and Power Dissipation (1)

			RESULTS AT V _S = 5V							
PARAMETER		EQUATION	A1, B1 DEVICES	A2, B2 DEVICES	A3, B3 DEVICES	A4, B4 DEVICES	A5, B5 DEVICES			
G	Gain		10V/V	20V/V	50V/V	100V/V	200V/V			
V _{SENSE}	Ideal differential input voltage	V _{SENSE} = V _{OUT} / G	500mV	250mV	100mV	50mV	25mV			
R _{SENSE}	Current sense resistor value	R _{SENSE} = V _{SENSE} / I _{MAX}	50mΩ	25mΩ	10mΩ	5mΩ	2.5mΩ			
P _{SENSE}	Current-sense resistor power dissipation	R _{SENSE} × I _{MAX} 2	5W	2.5W	1W	0.5W	0.25W			

(1) Design example with 10A full-scale current with maximum output voltage set to 5V.

8.2 Typical Application

The INA296x-Q1 is a bidirectional, current-sense amplifier capable of measuring currents through a resistive shunt with common-mode voltages from –5 V to +110 V.

8.2.1 Current Sensing in a Solenoid Application

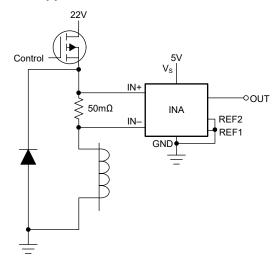


Figure 8-1. Solenoid Drive Application Circuit

8.2.1.1 Design Requirements

In this example application, the common-mode voltage ranges from 0V to 22V. The maximum sense current is 1.25A, and a 5V supply is available for the INA296x-Q1. Following the design guidelines from R_{SENSE} and Device Gain Selection, a R_{SENSE} of $50m\Omega$ and a gain of 20V/V are selected to provide good output dynamic range. Table 8-2 lists the design setup for this application.

Table 8-2. Design Parameters

	<u> </u>					
DESIGN PARAMETERS	EXAMPLE VALUE					
Power supply voltage	5V					
Common mode voltage range	0V to 22V					
Maximum sense current	1.25A					
R _{SENSE} resistor	50mΩ					
Gain option	20V/V					

Product Folder Links: INA296A-Q1 INA296B-Q1

8.2.1.2 Detailed Design Procedure

The INA296x-Q1 is designed to measure current in a typical solenoid application. The INA296x-Q1 measures current across the $50m\Omega$ shunt that is placed at the output in series with solenoid. The INA296x-Q1 measures the differential voltage across the shunt resistor, and the signal is internally amplified with a gain of 20V/V. The output of the INA296x-Q1 is connected to the analog-to-digital converter (ADC) of an MCU to digitize the current measurements.

Solenoid loads are highly inductive and are often prone to failure. Solenoids are often used for position control, precise fluid control, and fluid regulation. Measuring real-time current on the solenoid continuously can indicate premature failure of the solenoid, which can lead to a faulty control loop in the system. Measuring high-side current also indicates if there are any ground faults on the solenoid or the FETs that can be damaged in an application. The INA296x-Q1, with high bandwidth and slew rate, can be used to detect fast overcurrent conditions to prevent the solenoid damage from short-to-ground faults.

8.2.1.3 Application Curve

Figure 8-2 shows the output response of a solenoid.

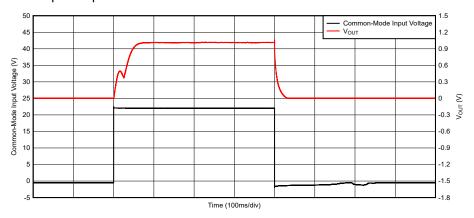


Figure 8-2. Solenoid Control Current Response

8.3 Power Supply Recommendations

The INA296x-Q1 makes accurate measurements beyond the connected power-supply voltage (V_S) because the inputs (IN+ and IN-) can operate anywhere between –5V and 110V independent of V_S . For example, with the V_S power supply equal to 5V, the common-mode voltage of the measured shunt can be as high as 110V.

8.3.1 Power Supply Decoupling

Place the power-supply bypass capacitor as close to the supply and ground pins as possible. TI recommends a bypass capacitor value of 0.1µF. Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.

8.4 Layout

8.4.1 Layout Guidelines

Attention to good layout practices is always recommended.

- Connect the input pins to the sensing resistor using a Kelvin or 4-wire connection. This connection technique
 makes sure that only the current-sensing resistor impedance is detected between the input pins. Poor routing
 of the current-sensing resistor commonly results in additional resistance present between the input pins.
 Given the very low ohmic value of the current sense resistor, any additional high-current carrying impedance
 can cause significant measurement errors.
- Place the power-supply bypass capacitor as close to the device power supply and ground pins as possible.
 The recommended value of this bypass capacitor is 0.1µF. Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.



8.4.2 Layout Examples

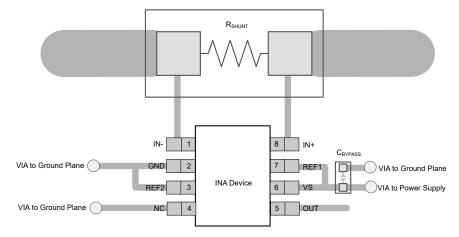


Figure 8-3. INA296x-Q1 SOT-23 (DDF), SOIC (D) and VSSOP (DGK) Package Recommended Layout

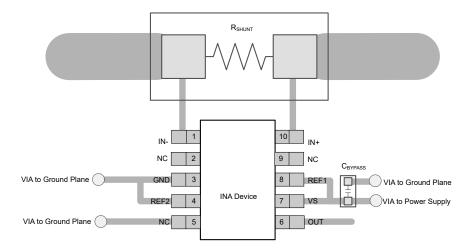


Figure 8-4. INA296x-Q1 10-Pin VSSOP (DGS) Package Recommended Layout

Submit Document Feedback

Copyright © 2024 Texas Instruments Incorporated



9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation see the following: Texas Instruments, INA296EVM, EVM user's guide

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (February 2024) to Revision C (December 2024)

Pag

- Updated the number format for tables, figures, and cross-references throughout the document.......
- Deleted the preview note from DGS package from Package Information table and throughout the data sheet 1

Changes from Revision A (August 2023) to Revision B (February 2024)

Page

Changes from Revision * (February 2023) to Revision A (August 2023)

Page

- Added the DGS package pin configuration......2



Added DGS package in recommended layout examples......24

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: INA296A-Q1 INA296B-Q1





28-Jan-2025 www.ti.com

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
INA296A1QDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2ZD3	Samples
INA296A1QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	3A7B	Samples
INA296A1QDGSRQ1	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3FTB	Samples
INA296A1QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	296A1Q	Samples
INA296A2QDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2ZE3	Samples
INA296A2QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	3A8B	Samples
INA296A2QDGSRQ1	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3FUB	Samples
INA296A2QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	296A2Q	Samples
INA296A3QDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2ZF3	Samples
INA296A3QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	3A9B	Samples
INA296A3QDGSRQ1	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3FVB	Samples
INA296A3QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	296A3Q	Samples
INA296A4QDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2ZG3	Samples
INA296A4QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	ЗААВ	Samples
INA296A4QDGSRQ1	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3FWB	Samples
INA296A4QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	296A4Q	Samples
INA296A5QDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2ZH3	Samples
INA296A5QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	3ABB	Samples
INA296A5QDGSRQ1	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3FXB	Samples
INA296A5QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	296A5Q	Samples





www.ti.com

28-Jan-2025

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
INA296B1QDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2ZI3	Samples
INA296B1QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	3ACB	Samples
INA296B1QDGSRQ1	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3FZB	Samples
INA296B1QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	296B1Q	Samples
INA296B2QDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2ZJ3	Samples
INA296B2QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	3ADB	Samples
INA296B2QDGSRQ1	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3G1B	Samples
INA296B2QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	296B2Q	Samples
INA296B3QDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2ZK3	Samples
INA296B3QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	3AEB	Samples
INA296B3QDGSRQ1	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3G2B	Samples
INA296B3QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	296B3Q	Samples
INA296B4QDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2ZL3	Samples
INA296B4QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	3AFB	Samples
INA296B4QDGSRQ1	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3G3B	Samples
INA296B4QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	296B4Q	Samples
INA296B5QDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2ZM3	Samples
INA296B5QDGKRQ1	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	3AGB	Samples
INA296B5QDGSRQ1	ACTIVE	VSSOP	DGS	10	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	3G4B	Samples
INA296B5QDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	296B5Q	Samples

⁽¹⁾ The marketing status values are defined as follows:

PACKAGE OPTION ADDENDUM

www.ti.com 28-Jan-2025

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF INA296A-Q1, INA296B-Q1:

Catalog: INA296A, INA296B

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product



www.ti.com 18-Dec-2024

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA296A1QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA296A1QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.15	3.1	1.55	4.0	8.0	Q3
INA296A1QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA296A1QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
INA296A2QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.15	3.1	1.55	4.0	8.0	Q3
INA296A2QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA296A2QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA296A2QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
INA296A3QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA296A3QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.15	3.1	1.55	4.0	8.0	Q3
INA296A3QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA296A3QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

www.ti.com 18-Dec-2024

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA296A4QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.15	3.1	1.55	4.0	8.0	Q3
INA296A4QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA296A4QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA296A4QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
INA296A5QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA296A5QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.15	3.1	1.55	4.0	8.0	Q3
INA296A5QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA296A5QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
INA296B1QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.15	3.1	1.55	4.0	8.0	Q3
INA296B1QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA296B1QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA296B1QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
INA296B2QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA296B2QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA296B2QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
INA296B3QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.15	3.1	1.55	4.0	8.0	Q3
INA296B3QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA296B3QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
INA296B4QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA296B4QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA296B4QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
INA296B5QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.15	3.1	1.55	4.0	8.0	Q3
INA296B5QDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
INA296B5QDGKRQ1	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA296B5QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



www.ti.com 18-Dec-2024



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA296A1QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296A1QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296A1QDGKRQ1	VSSOP	DGK	8	2500	356.0	356.0	35.0
INA296A1QDRQ1	SOIC	D	8	2500	353.0	353.0	32.0
INA296A2QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296A2QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296A2QDGKRQ1	VSSOP	DGK	8	2500	356.0	356.0	35.0
INA296A2QDRQ1	SOIC	D	8	2500	353.0	353.0	32.0
INA296A3QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296A3QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296A3QDGKRQ1	VSSOP	DGK	8	2500	356.0	356.0	35.0
INA296A3QDRQ1	SOIC	D	8	2500	353.0	353.0	32.0
INA296A4QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296A4QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296A4QDGKRQ1	VSSOP	DGK	8	2500	356.0	356.0	35.0
INA296A4QDRQ1	SOIC	D	8	2500	340.5	336.1	25.0
INA296A5QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296A5QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0



PACKAGE MATERIALS INFORMATION

www.ti.com 18-Dec-2024

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA296A5QDGKRQ1	VSSOP	DGK	8	2500	356.0	356.0	35.0
INA296A5QDRQ1	SOIC	D	8	2500	353.0	353.0	32.0
INA296B1QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296B1QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296B1QDGKRQ1	VSSOP	DGK	8	2500	356.0	356.0	35.0
INA296B1QDRQ1	SOIC	D	8	2500	353.0	353.0	32.0
INA296B2QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296B2QDGKRQ1	VSSOP	DGK	8	2500	356.0	356.0	35.0
INA296B2QDRQ1	SOIC	D	8	2500	353.0	353.0	32.0
INA296B3QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296B3QDGKRQ1	VSSOP	DGK	8	2500	356.0	356.0	35.0
INA296B3QDRQ1	SOIC	D	8	2500	353.0	353.0	32.0
INA296B4QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296B4QDGKRQ1	VSSOP	DGK	8	2500	356.0	356.0	35.0
INA296B4QDRQ1	SOIC	D	8	2500	340.5	336.1	25.0
INA296B5QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296B5QDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
INA296B5QDGKRQ1	VSSOP	DGK	8	2500	356.0	356.0	35.0
INA296B5QDRQ1	SOIC	D	8	2500	340.5	336.1	25.0





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187, variation BA.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





PLASTIC SMALL OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.





NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.





NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025. Texas Instruments Incorporated